Electronic Structure of a Single-Component Molecular Conductor $[Pd(ddt)_2]$ (dddt = 5,6-dihydro-1,4-dithiin-2,3-dithiolate) under High Pressure

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We examined the high-pressure electronic structure of a single-component molecular conductor $[Pd(dddt)_2]$ (dddt = 5,6-dihydro-1,4-dithiin-2,3-dithiolate) at room temperature, on the basis of the crystal structure determined by single-crystal synchrotron X-ray diffraction measurements at 5.9 GPa. The monoclinic unit cell contains four molecules that form two crystallographically independent molecular layers. A tight-binding model of an 8×8 matrix Hamiltonian gives an electronic structure as a Dirac electron system. The Dirac point describes a loop within the first Brillouin zone, and a nodal line semimetal is obtained. The noticeable property of the Dirac cone with a linear dispersion is shown by calculating the density of states (DOS). The Dirac cone in this system is associated with the crossing of highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) bands, which originates from the direct interaction between different molecular layers. This is a newly found mechanism in addition to the indirect interaction [J. Phys. Soc. Jpn., 86, 064705 (2017)]. The Dirac points emerge as a line when the HOMO and LUMO bands meet on the surface and the HOMO-LUMO couplings are absent. Such a mechanism is verified using a reduced model of a 4×4 matrix Hamiltonian. The deviation of the band energy (δE) at the Dirac point from the Fermi level is very small ($\delta E < 0.4$ meV). The nodal line is examined by calculating the parity of the occupied band eigenstates at time reversal invariant momentum (TRIM), which shows that the topological number is 1.

1. Introduction

Molecular conductors have simple and clear electronic structures where a simple extended Hückel tight-binding (TB) band picture is applicable.¹⁾ This is mainly because only one kind of frontier molecular orbital (HOMO or LUMO) in each molecule contributes to the formation of a conduction band in conventional molecular conductors, where HOMO and LUMO denote highest occupied molecular orbital and lowest unoccupied molecular orbital, respectively. In recent years, however, the number of molecular conductors that cannot be categorized as such a single-orbital system has been increasing. This means that we should expand our perception toward a multi-orbital system where more than two molecular orbitals in the same molecule contribute to electronic properties and the orbital degree of freedom plays an essential role.

A typical example of the multi-orbital system is a single-component molecular conductor. Molecules usually have a closed-shell electronic structure, which is the reason why they are stable in an isolated state. Therefore, it was believed that neutral closed-shell molecules do not self-assemble to form a metallic bond in a crystal and, therefore, the electron transfer between the frontier molecular orbital and other chemical species is indispensable for a metallic molecular crystal. Resultant molecular metals are no longer single-component, but they include other cations or anions to maintain the charge neutrality. If the energy difference between HOMO and LUMO is sufficiently small, however, the fully occupied HOMO band and the empty LUMO band can overlap, and an intramolecular electron transfer leads these bands to partially filled states. This idea has been confirmed by the observation of electron and hole Fermi surfaces in an ambient-pressure single-component molecular metal $[Ni(tmdt)_2]$ (tmdt = trimethylenetetrathiafulvalenedithiolate) by detecting the de Haas-van Alphen effect.^{2,3)} After this breakthrough, various singlecomponent molecular conductors have been developed using metal dithiolene complexes.⁴⁾ In metal dithiolene complexes with a planar central core, the HOMO is destabilized owing to the absence of the contribution from the metal d orbitals and the HOMO-LUMO gap is small (< 1 eV) in general.⁵⁾ Even in the case of metal dithiolene complexes, however, the HOMO and LUMO bands are mostly separated from each other, and a metallic state rarely emerges at ambient pressure. In a molecular crystal with a soft lattice, the application of high pressure can effectively enhance intermolecular transfer integrals and thus induce the overlap of the HOMO and LUMO bands. Indeed, an increasing number of singlecomponent molecular metals have been found under high pressure.^{6,7}Notably, an improvement of the diamond anvil cell (DAC) technique that provides high-quality quasi hydrostatic pressure drove the research forward.⁸⁾ Superconductivity in a single-component molecular crys-

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tal was also achieved under high pressure generated by DAC.⁹⁾ Thus, we realized a metallic/superconducting state in single-component molecular crystals. In these single-component molecular systems that we now focus on, molecules maintain their original molecular properties even in the high-pressure metallic state, and it is anticipated that the emergence of a metallic state itself can be well understood in the framework of the conventional TB band theory. It should be recognized that the deeper goal of the physical research on single-component molecular conductors is not just to obtain a conventional metallic state. What is really being put to the test is the possibility of unique physical properties that are built in the multi-orbital system.

In this sense, the discovery of a nodal line semimetal state in a single-component molecular conductor $[Pd(dddt)_2]$ (dddt = 5,6-dihydro-1,4-dithiin-2,3dithiolate) under high pressure has paved the way for the development of multi-orbital molecular conductors.^{10–15)} Indeed, after this discovery, a semimetal with open nodal lines has been found in another single-component molecular conductor $[Pt(dmdt)_2]$ (dmdt = dimethyltetrathiafulvalenedithiolate).^{16–18)} Nodal line semimetals where the conduction and valence bands touch each other along a line in the three-dimensional Brillouin zone have aroused broad interest owing to the possibility of topologically nontrivial states.¹⁹⁻²⁸ The crystal of the metal dithiolene complex $[Pd(ddt)_2]$ is an insulator at ambient pressure. The application of hydrostatic pressure using the DAC technique suppressed resistivity and activation energy. The temperature-independent resistivity observed at $12.6~\mathrm{GPa}$ triggered theoretical studies using first-principles calculations based on the density functional theory (DFT). The energy band structure for the optimized high-pressure structure indicates the emergence of the Dirac cones at 8 GPa, which is consistent with the zero-gap behavior observed in the resistivity measurement. The TB model based on extended Hückel molecular orbital calculations revealed that the Dirac cone formation is associated with the multi-orbital character, and the Dirac point describes a loop in the threedimensional Brillouin zone. The small deviation of the energy on the loop from the Fermi level gives hole and electron pockets, which means that the system is a nodal line semimetal. Although an unexpected relationship between the single-component molecular conductor and the nodal line semimetal has been disclosed, a concern is the absence of X-ray structural data of the $[Pd(dddt)_2]$ crystal determined under high pressure. The energy band calculations were based only on theoretically optimized cell parameters and atomic coordinates.

Recently, crystal structures of $[Pd(dddt)_2]$ at several pressures have been determined by single-crystal synchrotron X-ray diffraction measurements, details of which will be reported elsewhere. In this article, we examine the nodal line semimetal state of $[Pd(dddt)_2]$ at 5.9 GPa at room temperature on the basis of the determined crystal structure. This paper is organized as follows. In Sect. 2, we describe the TB model used in this work. In Sect. 3, first, the band structure is shown with a

H–H	L–L	H–L	
209.3	-1.9	-51.2	(stacking)
28.1	-12.4	19.9	Layer 1
	—	17.1	
49.9	-80.4	-67.2	(stacking)
10.8	8.1	9.3	Layer 2
	—	9.2	
-28.2	14.6	-20.1	
2.2	1.3	-1.7	Interlayer
15.4	12.7	14.1	
-3.9	15.8	-11.8	
	$\begin{array}{c} 209.3 \\ 28.1 \\ \\ 49.9 \\ 10.8 \\ \\ -28.2 \\ 2.2 \\ 15.4 \end{array}$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

detailed description of the mechanism of the Dirac cone formation and the resultant nodal line. Next, we present the density of states (DOS) and parity at TRIM, which are relevant to the nodal line. The conclusion is given in Sect. 4.

2. TB model

We carried out synchrotron X-ray diffraction measurements at several pressures and found that there is no marked structural phase transition up to 10.6 GPa. The cell volume measured at 5.9 GPa (1152.8 \AA^3) is close to that obtained by the DFT calculation for the 8 GPa structure (1147.5 $Å^3$), which is the reason why we focus on the 5.9 GPa structure. The determined cell parameters and atomic coordinates are listed in Appendix A. Figure 1 shows the molecular arrangement and intermolecular couplings in the $[Pd(dddt)_2]$ crystal. The unit cell contains four molecules (1, 2, 3, and 4), and each central Pd atom is located at the inversion center. The $[Pd(dddt)_2]$ molecules uniformly stack along the *b*-axis that is perpendicular to the *ac* plane. Crystallographically equivalent molecules form two types of layers, layer 1 (molecules 1 and 3) and layer 2 (molecules 2 and 4), both of which are parallel to the *ab* plane.

We construct a TB model for $[Pd(dddt)_2]$ using frontier molecular orbitals of four molecules in the unit cell, HOMOs (H1, H2, H3, H4) and LUMOs (L1, L2, L3, L4).

The TB model Hamiltonian is given by

$$H_{\text{TB}} = \sum_{i,j=1}^{N} \sum_{\alpha,\beta} t_{i,j;\alpha,\beta} |i,\alpha\rangle \langle j,\beta|$$

$$= \sum_{\boldsymbol{k}} \sum_{\alpha,\beta} h_{\alpha,\beta}(\boldsymbol{k}) |\boldsymbol{k},\alpha\rangle \langle \boldsymbol{k},\beta|$$

$$= \sum_{\boldsymbol{k}} |\Phi(\boldsymbol{k})\rangle \hat{H}(\boldsymbol{k}) \langle \Phi(\boldsymbol{k})| , \qquad (1)$$

where $t_{i,j;\alpha,\beta}$ are transfer energies between nearestneighbor sites and $\langle i, \alpha |$ is a state vector. $\alpha, \beta = \text{H1}$, H2, ..., L3, and L4. $h_{\alpha,\beta}(\mathbf{k})$ denotes a Fourier transform of $t_{i,j;\alpha,\beta}$ with a complex conjugate relation $h_{\alpha,\beta}(\mathbf{k}) = \overline{h_{\beta,\alpha}(\mathbf{k})}$, where $\mathbf{k} = k_x a^* + k_y b^* + k_z c^* \equiv (k_x, k_y, k_z)$, and $2\pi k_x = \mathbf{ka}, 2\pi k_y = \mathbf{kb}$, and $2\pi k_z = \mathbf{kc}$. $\hat{H}(\mathbf{k})$ is an

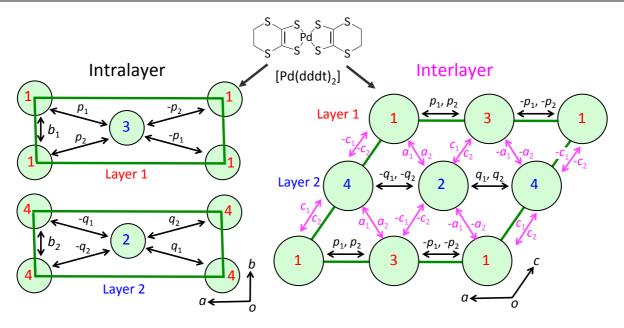


Fig. 1. (Color online) Molecular arrangement and intermolecular couplings that explain crystal structure of $[Pd(dddt)_2]$.¹¹⁾

 8×8 matrix Hamiltonian, where $h_{\alpha,\beta} = \left(\hat{H}(\boldsymbol{k})\right)_{\alpha,\beta}$ and $\langle \Phi(\mathbf{k}) | = (\langle \text{H1} |, \langle \text{H2} |, \langle \text{H3} |, \langle \text{H4} |, \langle \text{L1} |, \langle \text{L2} |, \langle \text{L3} |, \langle \text{L4} |).$ In terms of $X = e^{i\mathbf{k}\mathbf{a}}$, $Y = e^{i\mathbf{k}\mathbf{b}}$, and $Z = e^{i\mathbf{k}\mathbf{c}}$, matrix elements $h_{\alpha,\beta}(\mathbf{k})$ are given in Appendix B. The energy difference between HOMO and LUMO is taken as ΔE = 0.696 eV to reproduce the energy band obtained by the DFT calculation. Interlayer and intralayer transfer energies in matrix elements $h_{\alpha,\beta}(\mathbf{k})$ are shown in Table I, which are estimated by the extended Hückel method. The interlayer transfer energies in the c direction are given by a (molecules 1 and 2, and molecules 3 and 4) and c (molecules 1 and 4, and molecules 2 and 3). The intralayer transfer energies parallel to the *ab* plane are given by p (molecules 1 and 3), q (molecules 2 and 4), and b. These transfer energies are classified into HOMO– HOMO (H), LUMO-LUMO (L), and HOMO-LUMO (HL).

These transfer energies are rather different from those of the previous model based on the theoretically optimized structure at 8 GPa. Notably, there are significant contributions from the direct interlayer HOMO-LUMO couplings, which provide the elements $h_{\rm H1,L2}, h_{\rm H1,L4}, h_{\rm H3,L2}$, and $h_{\rm H3,L4}$ and those being the complex conjugate elements. In the previous model in Ref. 11, however, these elements are negligibly small and thus discarded. The indirect interlayer HOMO-LUMO couplings play an important role in the Dirac cone formation instead. This is obtained by a second-order perturbation in terms of the intralayer HOMO-LUMO and interlayer LUMO-LUMO or HOMO-HOMO couplings, e.g., a combination of $h_{\text{H1,L3}}$ and $h_{\text{L3,L2}}$. The direct interlayer HOMO-LUMO couplings also give the off-diagonal elements of a reduced model of a 4×4 Hamiltonian, which we will discuss later. Since the symmetry of the HOMO (H) (LUMO (L)) is odd (even) with respect to the Pd atom, the matrix element of H–L (H–H and L–L) is the odd (even) function with respect to k.

The energy band $E_j(\mathbf{k})$ and the wave function $\Psi_j(\mathbf{k})$, $(j = 1, 2, \dots, 8)$ are calculated from

$$\hat{H}(\boldsymbol{k})\Psi_{j}(\boldsymbol{k}) = E_{j}(\boldsymbol{k})\Psi_{j}(\boldsymbol{k}) , \qquad (2)$$

where $E_1 > E_2 > \cdots > E_8$. Since the energy band formed by fully occupied HOMOs and empty LUMOs is half-filled, we examine the gap defined by

$$E_g(\boldsymbol{k}) = \min(E_4(\boldsymbol{k}) - E_5(\boldsymbol{k})), \qquad (3)$$

for all \boldsymbol{k} in the Brillouin zone. The Dirac point \boldsymbol{k}_D is obtained from $E_g(\boldsymbol{k}_D) = 0$, which leads to a nodal line.

We also examine the nodal line using an effective Hamiltonian given by

$$H_{\rm eff}(\mathbf{k}) = \begin{pmatrix} f_0(\mathbf{k}) + f_3(\mathbf{k}) & f_2(\mathbf{k}) \\ f_2(\mathbf{k}) & f_0(\mathbf{k}) - f_3(\mathbf{k}) \end{pmatrix},$$
(4)

where $f_0(\mathbf{k})$, $f_3(\mathbf{k})$, and $f_2(\mathbf{k})$ are calculated as follows. The Hamiltonian is divided into three 8 × 8 matrices as

$$\hat{H} = \hat{H}_{\rm H-H} + \hat{H}_{\rm L-L} + \hat{H}_{\rm H-L} ,$$
 (5)

where $[\hat{H}_{H-H}]_{\alpha,\beta} = h_{\alpha,\beta}$ with $\alpha,\beta = H1, \cdots H4$ and 0 otherwise, $[\hat{H}_{L-L}]_{\alpha,\beta} = h_{\alpha,\beta}$ with $\alpha,\beta = L1, \cdots L4$ and 0 otherwise, and $[\hat{H}_{H-L}]_{\alpha,\beta} = h_{\alpha,\beta}$ with $\alpha = H1 \cdots, H4$ (or L1, $\cdots L4$) and $\beta = L1, \cdots L4$ (or H1 $\cdots, H4$) and 0 otherwise. We define $E_{H}(\mathbf{k})$ ($E_{L}(\mathbf{k})$) as the maximum (minimum) eigenvalue of HOMO (LUMO), which is obtained from $\hat{H}_{H-H} | \Psi_{H} \rangle = E_{H}(\mathbf{k}) | \Psi_{H} \rangle$ and $\hat{H}_{L-L} | \Psi_{L} \rangle = E_{L}(\mathbf{k}) | \Psi_{L} \rangle$. Note that $| \Psi_{H} \rangle$ and $| \Psi_{L} \rangle$ are eigenvectors at each \mathbf{k} . Thus, we obtain $f_{0}(\mathbf{k}) =$ $(E_{H}(\mathbf{k}) + E_{L}(\mathbf{k}))/2, f_{3}(\mathbf{k}) = (E_{H}(\mathbf{k}) - E_{L}(\mathbf{k}))/2$, and $f_{2}(\mathbf{k}) = \langle \Psi_{H} | H_{H-L} | \Psi_{L} \rangle = \langle \Psi_{L} | H_{H-L} | \Psi_{H} \rangle$. The quantities $f_{0}(\mathbf{k}), f_{2}(\mathbf{k})$, and $f_{3}(\mathbf{k})$ can be taken as real.²⁹ Note that $f_{0}(\mathbf{k}) = f_{0}(-\mathbf{k})$, and $f_{3}(\mathbf{k}) = -f_{2}(-\mathbf{k})$ owing to the time reversal symmetry and $f_{2}(\mathbf{k}) = -f_{2}(-\mathbf{k})$ owing

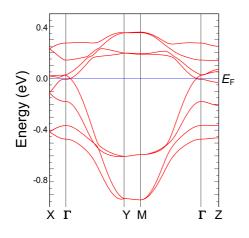


Fig. 2. (Color online) Energy band structure of $[{\rm Pd}(dddt)_2]$ at 5.9 GPa

to the different parity of HOMO and LUMO. The nodal line is obtained from $f_3(\mathbf{k}) = 0$ and $f_2(\mathbf{k}) = 0$. In the next section, we examine these surfaces of $f_2(\mathbf{k}) = 0$ and $f_3(\mathbf{k}) = 0$ in the three-dimensional momentum space.

3. Results

3.1 Band structure with Dirac cone

In Fig. 2, the energy band structure is shown, where the origin of the energy is taken at the Fermi energy $E_{\rm F}$. Despite the rather large differences in transfer energies, the essential shape of the band structure, including the nodal line semimetal state, is very similar to that of the previous model. The band crossing occurs on the line between TRIMs Γ and Y. The corresponding energy is slightly lower than the Fermi energy $(E_{\rm F})$ leading to an electron pocket.

Here, we mention the Dirac point obtained from $E_g(\mathbf{k}_{\rm D}) = 0$, i.e., $E_4(\mathbf{k}_{\rm D}) = E_5(\mathbf{k}_{\rm D})$, which provides a line in the three-dimensional momentum space. Figure 3 shows Dirac points forming a closed line (loop), which is symmetric with respect to $k_y = 0$. Compared with the previous case in Ref. 11, the loop is almost coplanar and located within the first Brillouin zone. The variation of the energy at the Dirac point along the line is very small, as shown in the next paragraph.

Results of the calculation are summarized as follows. The energy band of the 8×8 model in Fig. 2 reproduces the overall behavior of the previous result that is obtained on the basis of the DFT.¹⁰ This is partially because the nature of the main transfer energies including $b1_{\rm H}$ and $b2_{\rm L}$ does not change. Dirac points form a nodal loop within the first Brillouin zone (Fig. 3), which well reproduces the nature of the DFT band structure. The axis of the cone changes along the line, and the axis at $k_z = 0$ is almost perpendicular to that at $k_y = 0$. The energy at the Dirac points varies along the nodal line but the deviation from the Fermi energy is very small, $\sim \pm 0.4$ meV, which is smaller (electron pocket) around $k_z = 0$ and larger (hole pocket) around $k_y = 0$. Thus, the electronic state is expected to have a two-dimensional characteristic of the Dirac cone, as shown later in DOS.

To consider a role of the direct interlayer HOMO-

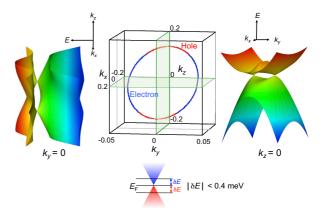


Fig. 3. (Color online) Nodal line and a pair of Dirac cones at $k_z = 0$ and $k_y = 0$ in $[Pd(dddt)_2]$ at 5.9 GPa. The hole-like characteristic is indicated in red and the electron-like characterisic in blue.

LUMO couplings in the Dirac cone formation, we examine a reduced 4×4 Hamiltonian obtained using Eq. (1) by discarding the states $|\text{H2}\rangle$, $|\text{H4}\rangle$, $|\text{L1}\rangle$, and $|\text{L3}\rangle$, i.e.,

$$H_{\text{red}} = \sum_{\boldsymbol{k}} \sum_{\alpha',\beta'} h_{\alpha',\beta'}(\boldsymbol{k}) |\boldsymbol{k},\alpha'\rangle \langle \boldsymbol{k},\beta'|$$
$$= \sum_{\boldsymbol{k}} |\Phi_4(\boldsymbol{k})\rangle \hat{H}_{4\times 4}(\boldsymbol{k}) \langle \Phi_4(\boldsymbol{k})| , \qquad (6)$$

with $\alpha', \beta' = H1, H3, L2, and L4, and (\langle \Phi_4(\mathbf{k}) | =$ $\langle H1|, \langle H3|, \langle L2|, \langle L4| \rangle$. This reduced model of the 4 \times 4 Hamiltonian well reproduces the four energy bands shown in Fig. 2 around the Fermi level [Figs. 4(a) and 4(b)]. This means that the Dirac points originate from the HOMO bands in layer 1 and the LUMO bands in layer 2. Figures 4(c) and 4(d) show that the Dirac cone vanishes when the HOMO–LUMO couplings become zero $(h_{\text{H1,L2}} = h_{\text{H1,L4}} = h_{\text{H3,L2}} = h_{\text{H3,L4}} = 0)$. Figures 4(b) and 4(d) show that the Dirac points (nodal line) emerge when the HOMO and LUMO bands meet without the HOMO-LUMO couplings on the special points (the Dirac points). That is, the nodal line is an intersection of the surface of $f_3(\mathbf{k}) = 0$ and that of $f_2(\mathbf{k}) =$ 0, each of which forms a cylinder and a plane in the three-dimensional momentum space, respectively (Fig. 5). Note that Fig. 5 shows a qualitative behavior, since the surfaces, i.e., $f_2(\mathbf{k}) = 0$ and $f_3(\mathbf{k}) = 0$, are evaluated by the perturbational method.

Furthermore, the global band structure shown in Fig. 6, in which the direct HOMO–LUMO couplings corresponding to the 4×4 model are discarded, still resembles that shown in Fig. 2. This finding also suggests an additional mechanism of forming the Dirac point via a HOMO–LUMO interaction through a process of 2nd-order perturbation, as demonstrated in Ref. 10. We return to this point later in the discussion of DOS.

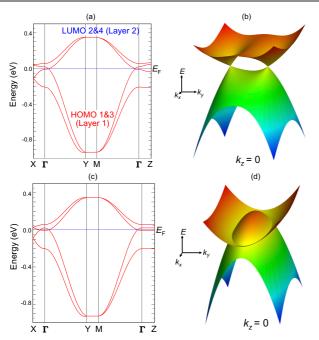


Fig. 4. (Color online) Band dispersion (a) and Dirac cones at $k_z = 0$ (b) for the 4×4 model. Band dispersion (c) and band energy dispersion surface at $k_z = 0$ for the 4×4 model without HOMO–LUMO couplings ($h_{\rm H1,L2} = h_{\rm H1,L4} = h_{\rm H3,L2} = h_{\rm H3,L4} = 0$) at $k_z = 0$ (d)

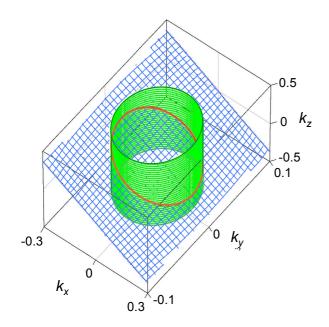


Fig. 5. (Color online) Intersection of HOMO and LUMO bands $[f_3(\mathbf{k}) = 0$: green cylinder], surface on which HOMO–LUMO couplings are zero $[f_2(\mathbf{k}) = 0$: blue plane], and nodal line (red line) in the 4×4 model

3.2 DOS

We examine DOS $D(\omega)$ per unit cell, which is defined as

$$D(\omega) = \frac{1}{N} \sum_{\boldsymbol{k}} \sum_{\gamma} \delta(\omega - E_{\gamma}(\boldsymbol{k})) .$$
 (7)

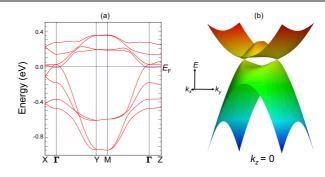


Fig. 6. (Color online) Band dispersion (a) and Dirac cones at $k_z=0$ (b) for the 8×8 model in the case of $h_{\rm H1,L2}=h_{\rm H1,L4}=h_{\rm H3,L2}=h_{\rm H3,L4}=0$

A chemical potential μ corresponding to a half-filled band is obtained from $4 = \int_{-\infty}^{\mu} d\omega D(\omega)$.

Figure 7 shows DOS for both the 8×8 Hamiltonian [line (1)] and 4×4 Hamiltonian [line (2)], where the latter consists of four bases, namely, $|H1\rangle$, $|H3\rangle$, $|L2\rangle$, and $|L4\rangle$. A good coincidence of DOS between the 8 \times 8 and 4×4 Hamiltonians is found for $-0.01 < \omega - \mu < 0.005$. This suggests the validity of the 4×4 Hamiltonian to describe the physical quantities at low temperatures. The difference in the global DOS between lines (1) and (2) is apparent for large $\omega - \mu (> 0)$, but the DOS for line (1) and that for line (2) are similar qualitatively, suggesting that the direct HOMO-LUMO interaction is crucial for the present Dirac electron system. This can be understood by comparings the DOSs for lines (1) and (2) with that for line (3), which is obtained by discarding the direct HOMO–LUMO interaction in the 8×8 Hamiltonian [Eq. (1]. Line (3) corresponds to the energy band shown in Fig. 6, and is similar to that in a previous paper.¹² There is a qualitative difference in DOS between lines (1) and (3) in the sense that the linear dependence of DOS around $\omega = \mu$ in lines (1) and (2) suggests an almost zero-gap state (ZGS) and is robust, i.e., displaying a wide energy region of linear dependence owing to the direct HOMO-LUMO interaction, which is in contrast to that in line (3) without the direct HOMO-LUMO interaction. A detailed analysis close to $\omega = \mu$ shows that the deviation of $D(\omega)$ from that with the linear dependence occurs in the narrow region of $|\omega - \mu| < 0.001$, suggesting that the variation of the energy on the nodal line is less than 0.001.

Here, we note that such a linear dependence of DOS has been found in the two-dimensional organic conductor α -ET₂I₃, which is the first material of Dirac electrons in a molecular conductor.^{30–32} The similarity of DOS for Pd(ddt)₂] and that for α -ET₂I₃ suggests that such a three-dimensional nodal line semimetal shares a common feature with the two-dimensional Dirac cone.

Moreover, we note that the linear dependence is given by $D(\omega) = K|\omega - \mu|$ with a coefficient $K \propto v^{-2}$, where v denotes an average velocity of the Dirac cone. Since Kof lines (1) and (2) is smaller than that of line (3), the former velocity is larger than the latter one, suggesting that in Eq. (4), $f_2(\mathbf{k})$ of the former is larger than that of the latter. This is reasonable since the direct HOMO–

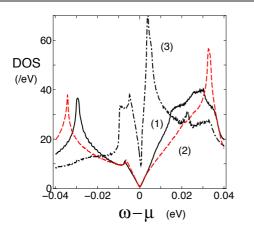


Fig. 7. (Color online) DOS $D(\omega)$ per unit cell for the 8 × 8 Hamiltonian (solid line) (1), and 4 × 4 Hamiltonian (dashed line) (2). The chemical potential μ is given by $\mu = 0.5053$ for the 8 × 8 model and 0.5095 for the 4 × 4 model. Around $\omega - \mu$, the behavior $D(\omega) = K|\omega - \mu|$ with a constant K(>0) is seen owing to a Dirac cone, where a small deviation close to $\omega - \mu$ comes from the energy variation on the nodal line. The dot-dashed line (3) denotes DOS without the interlayer H-L interaction, where $\mu = 0.5079$.

LUMO interaction is present in lines (1) and (2) but is absent in line (3).

3.3 Parity at TRIM

To analyze the Dirac point, we calculate the parity at the TRIM given by G/2 with G being the reciprocal lattice vector, where G/2 = (0,0,0), (1/2,0,0), (0,1/2,0), and (1/2,1/2,0) correspond to the Γ , X, Y, and M points, and G/2 = (0,0,1/2), (1/2,0,1/2), (0,1/2,1/2), and (1/2,1/2,1/2) correspond to the Z, D, C, and E points, respectively.

The inversion with respect to a Pd atom of molecule 1 in the crystal structure gives the matrix for the translation of the base (H1, H2, \cdots , L4), $\hat{P}(\mathbf{k})$, expressed as¹¹)

$$\hat{P}(\boldsymbol{k}) = \begin{pmatrix} \hat{P}_1(\boldsymbol{k}) & 0\\ 0 & -\hat{P}_1(\boldsymbol{k}) \end{pmatrix}, \quad (8)$$

where $\hat{P}_1(\mathbf{k})$ denotes a 4 ×4 matrix,

$$\hat{P}_{1}(\boldsymbol{k}) = \begin{pmatrix} -1 & 0 & 0 & 0\\ 0 & -XYZ & 0 & 0\\ 0 & 0 & -XY & 0\\ 0 & 0 & 0 & -\bar{Z} \end{pmatrix}.$$
(9)

The relation $(\hat{P}(\mathbf{k}))_{Hj,Hj} = -(\hat{P}(\mathbf{k}))_{Lj,Lj}$ for j=1, 2, 3, and 4 comes from the fact that the HOMO has an ungerade symmetry and the LUMO has a gerade symmetry. The eigenvalue and eigenfunction of $\hat{P}(\mathbf{k})$ are obtained from ($\alpha = \text{H1}, \text{H2}, \dots, \text{L4}$)

$$\hat{P}(\boldsymbol{k})u_{\alpha}(\boldsymbol{k}) = p_{\alpha}(\boldsymbol{k})u_{\alpha}(\boldsymbol{k}) , \qquad (10)$$

where $p_{\alpha}(\mathbf{k}) = (\hat{P}(\mathbf{k}))_{\alpha,\alpha}, \quad u_{\mathrm{H}1}(\mathbf{k}) = u_1 = (1, 0, 0, 0, 0, 0, 0)^t, \quad u_{\mathrm{H}2} = u_2 = (0, 1, 0, 0, 0, 0, 0)^t, \cdots,$ and $u_{\mathrm{L}4} = u_8 = (0, 0, 0, 0, 0, 0, 0, 1)^t$. At the TRIM, one obtains $p_{\alpha}(\mathbf{G}/2) = p_l = +(-)$, which gives an even (odd) Since $[\hat{P}(\mathbf{G}/2), \hat{H}(\mathbf{G}/2)] = 0$, $\Psi_j(\mathbf{G}/2)$ in Eq. (2) is also an eigenfunction of $\hat{P}(\mathbf{G}/2)$. The corresponding equation at the TRIM is given by

$$\hat{P}(\boldsymbol{G}/2)\Psi_{j}(\boldsymbol{G}/2) = E_{P}(j,\boldsymbol{G}/2)\Psi_{j}(\boldsymbol{G}/2) , \qquad (11)$$

with $E_P(j, \mathbf{G}/2) = +(-)$, which denotes an even (odd) parity. In terms of $u_l(\mathbf{G}/2)$, $\Psi_j(\mathbf{G}/2)$ is expressed as

$$\Psi_j(\mathbf{G}/2) = \sum_l d_{j,l}(\mathbf{G}/2)u_l(\mathbf{G}/2) .$$
 (12)

Since $\hat{P}(\mathbf{G}/2)u_l(\mathbf{G}/2) = p_l(\mathbf{G}/2)u_l(\mathbf{G}/2)$ with $p_l(\mathbf{G}/2) = \pm$, it turns out that $d_{j,l}(\mathbf{G}/2) = 0$ for $p_l(\mathbf{G}/2) \neq E_P(j, \mathbf{G}/2)$. Thus, the wave function for $E_j(\mathbf{G}/2)$ is given by a linear combination of the base $u_l(\mathbf{G}/2)$, which has the same parity as $E_P(j, \mathbf{G}/2)$. From Eqs. (11) and (12), $E_P(j, \mathbf{G}/2)$ is estimated as

$$E_P(j, \mathbf{G}/2) = \Psi_j(\mathbf{G}/2)^{\dagger} \hat{P}(\mathbf{G}/2) \Psi_j(\mathbf{G}/2)$$

= $\sum_{l=1}^8 p_l(\mathbf{G}/2) |d_{j,l}|^2$, (13)

which is utilized for the present numerical calculation. $E_P(j, \mathbf{G}/2)$ is shown as a function of $E_j(\mathbf{G}/2)$ for the respective TRIM. The sign of some elements in Table III is different from that of a previous calculation.¹¹⁾ However, as shown later, the resultant conditions for the Dirac points are unchanged, since both share a common feature of a nodal line. Note that $\sum_j P_{E_j}(\mathbf{G}/2) = 0$ for the respective TRIM. For the wave function $\Psi_j(\mathbf{G}/2)$ in Eq. (11) at the Γ and M points, the even (odd) parity corresponds to LUMO (HOMO).

To examine the nodal loop between $E_4(\mathbf{k})$ and $E_5(\mathbf{k})$, we calculate P_{δ} [$\delta = 1$ for $k_z = 0$, $\delta = 2$ for $k_y = 0$, and $\delta = 3$ for $k_z = 0.5$], which is defined as¹¹)

$$P_{1} = \prod_{j=5}^{8} E_{P}(j,\Gamma) E_{P}(j,\mathbf{X}) E_{P}(j,\mathbf{Y}) E_{P}(j,\mathbf{M}) ,$$
(14a)

$$P_{2} = \prod_{j=5}^{8} E_{P}(j, \mathbf{Z}) E_{P}(j, \Gamma) E_{P}(j, \mathbf{X}) E_{P}(j, \mathbf{D}) ,$$
(14b)

$$P_{3} = \prod_{j=5}^{8} E_{P}(j, \mathbf{Z}) E_{P}(j, \mathbf{D}) E_{P}(j, \mathbf{E}) E_{P}(j, \mathbf{C}) .$$
(14c)

Since we examine the Dirac point of the level crossing between E_4 and E_5 bands owing to a half-filled band, we take j = 5, 6, 7, and 8. Each P_{δ} denotes a quantity assigned on a plane including the four corresponding TRIMs. The condition for the Dirac point between E_4 and E_5 is given by $P_j = \pm 1.^{33}$ When $P_j = -1$, the number of pairs of Dirac points between E_4 and E_5

Table II. Parity $p_l(\mathbf{G}/2)$, where $\hat{P}(\mathbf{G}/2)u_l(\mathbf{G}/2)$ $p_l(\mathbf{G}/2)u_l(\mathbf{G}/2)$.

	u_1	u_2	u_3	u_4	u_5	u_6	u_7	u_8
Г	_	_	_	_	+	+	+	+
Х	_	+	+	_	+	_	_	+
Υ	_	+	+	_	+	_	_	+
Μ	_	_	_	_	+	+	+	+
Z	_	+	_	+	+	_	+	_
D	_	_	+	+	+	+	_	_
\mathbf{C}	_	_	+	+	+	+	_	_
Ε	_	+	_	+	+	_	+	_

Table III. Parity $E_P(j, \mathbf{G}/2)(=\pm)$ of 8 x 8 Hamiltonian at P = 5.9 GPa as the function of $E_j(j = 1, ..., 8)$ and $\mathbf{G}/2$ (= $\Gamma, ..., E$).

	E_1	E_2	E_3	E_4	E_5	E_6	E_7	E_8
Г	+	+	_	+	+	_	_	_
Х	+	_	+	_	_	+	+	_
Υ	+	_	+	_	_	+	_	+
Μ	+	+	+	+	_	-	-	_
Ζ	+	+	_	_	_	_	+	+
D	+	-	+	-	_	+	-	+
\mathbf{C}	+	-	+	-	_	+	-	+
Е	_	_	+	+	+	+	_	_

is odd,^{34,35}) implying that the topological number is 1. The condition for a nodal line is given by¹¹)

$$P = P_1 P_3 = -1 . (15)$$

Note that Eqs. (14a)–(14c) describe the condition of the Dirac point on the planes of $k_z = 0$ (TRIM with the Γ , X, Y, and M points), $k_y = 0$ (TRIM with the Z, Γ , X, and D points), and $k_z = 0.5$ (TRIM with the Z, D, C, and E points), respectively. The nodal closed loop is found for $P_1 = -1$, $P_2 = -1$, and $P_3 = 1$. Note that the parity for the nodal line semimetal of [Pt(dmdt)_2] with an open line¹⁶ is given by $P = 1^{17}$ instead of Eq. (15).

Here, we examine the reduced 4×4 Hamiltonian with the bases of H1, H3, L2, and L4 by discarding the elements corresponding to H2, H4, L1, and L3. Instead of eight bands, we obtain the four bands $E_1(\mathbf{k})$, $E_2(\mathbf{k})$, $E_3(\mathbf{k})$, and $E_4(\mathbf{k})$. In this case, the inversion matrix is given by

$$\hat{P}_{4\times4}(\boldsymbol{k}) = \begin{pmatrix} -1 & 0 & 0 & 0\\ 0 & -XY & 0 & 0\\ 0 & 0 & XYZ & 0\\ 0 & 0 & 0 & \bar{Z} \end{pmatrix}.$$
(16)

The parities are listed in Table IV. Noting that the filled band is given by E_j with j=3 and 4, we obtain also the closed nodal line since $P(k_z = 0) = -1$, $P(k_y = 0) = -1$, and $P(k_z = \pi) = 1$.

Here, we comment on the parity of the 4 × 4 reduced Hamiltonian, which is different from the conventional one.³⁵⁾ The relation $\sum_{l,G} p_l(G/2) = 0$ holds for

Table IV. Parity $E_P(j, G/2)(= \pm)$ of 4 x 4 Hamiltonian with H1, H3, L2, and L4.

	E_1	E_2	E_3	E_4
Г	+	_	+	_
Х	_	+	_	+
Y	_	+	_	+
Μ	+	+	_	_
\mathbf{Z}	_	_	_	_
D	_	+	_	+
\mathbf{C}	_	+	_	+
Ε	_	-	_	_

the latter case but does not for $\mathbf{G}/2 = \mathbf{Z}$ and \mathbf{E} of the former, in which the Pd atom is not the inversion center because H2, H4, L1, and L3 are discarded. Thus, we construct an effective 8×8 Hamiltonian by adding 4 bases, namely, H2, H4, L1, and L3 with only site energies, which are much higher (lower) than E_i $(j = 1, \dots, 4)$ for H2 and H4 (L1 and L3). In this case, the energies are obtained as $E_a > E_b \gg E_1 > E_2 > E_3 > E_4 \gg$ $E_c > E_d$, where E_1, \cdots, E_4 are the same as those of the 4 \times 4 Hamiltonian. We obtain the additional parity as $[E_P(j,\Gamma), E_P(j,\mathbf{X}), E_P(j,\mathbf{Y}), E_P(j,\mathbf{M}), E_P(j,\mathbf{Z}),$ $E_P(j, \mathbf{D}), E_P(j, \mathbf{C}), E_P(j, \mathbf{E})] = (-, -, -, -, -, -, -, -)$ for $E_j = E_a$, (-, +, +, -, -, +, +, -) for $E_j = E_b$, (+, -, -, +, -, +, -, +) for $E_j = E_c$, and (+, +, +, +, -, -, -, -) for $E_j = E_d$. We find that the resultant parity satisfies $\sum_{l,G} p_l(G/2) = 0$, and the parity relevant to E_1, E_2, E_3 , and E_4 remains the same as that in Table IV.

4. Conclusions

We have examined a nodal line semimetal in a singlecomponent molecular conductor $[Pd(dddt)_2]$ under high pressure, which consists of two crystallographically independent molecular layers. On the basis of the synchrotron X-ray diffraction measurements at 5.9 GPa, we derive the TB model with both 8×8 and 4×4 matrix Hamiltonians. We have shown a mechanism of the nodal line formation, which is obtained as an intersection between a crossing plane of the HOMO and LUMO bands and a plane of vanishing HOMO-LUMO interactions. Compared with our previous paper, our new finding is the crucial role of the direct HOMO-LUMO interaction between layers 1 and 2, which results in the robust Dirac cone within an energy height of ~ 0.01 eV. This finding was verified by calculating DOS, which also provides a width of energy band along the nodal line of less than 0.4 meV. Finally, in terms of topology, we examined the parity for the nodal line in both 8×8 and 4×4 matrix Hamiltonians. The former Hamiltonian is essentially the same as the previous one, wheras the latter is different from the conventional 4×4 matrix Hamiltonian but can be interpreted in a consistent manner.

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Table A.1. Fractional atomic coordinates.

Table A	Fractio	onal atomic c	coordinates.
Atom	x	y	z
Pd1	0.00000	0.00000	0.00000
S1	0.10040	-0.1850	-0.04520
S2	0.06100	-0.2850	0.11400
S3	0.24700	-0.5960	0.00620
S4	0.20400	-0.7030	0.18400
C1	0.15600	-0.42706	0.02800
C2	0.14800	-0.4640	0.10100
C3	0.30000	-0.8460	0.09100
C4	0.31100	-0.6930	0.17600
H3A	0.26727	-1.0371	0.084043
H3B	0.35779	-0.89871	0.091206
H4A	0.33099	-0.48076	0.17840
H4B	0.35293	-0.80806	0.22127
Pd2	0.50000	0.5000	0.00000
S5	0.60930	0.8400	0.05810
S6	0.45870	0.5950	0.10490
S7	0.67580	1.2230	0.20240
$\mathbf{S8}$	0.50200	0.9570	0.24860
C5	0.60300	0.9530	0.14700
C6	0.52900	0.8510	0.16600
C7	0.67900	1.1850	0.30800
C8	0.58400	1.2150	0.30300
H7A	0.70275	0.9846	0.33026
H7B	0.71493	1.3461	0.34237
H8A	0.56407	1.4195	0.28101
H8B	0.58671	1.2140	0.35933

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Appendix A: Crystal data of $[Pd(dddt)_2]$ at 5.9 GPa

Space group: $P2_1/n$

Lattice constants: $a_{\rm o}=16.48,\ b_{\rm o}=4.3102,\ c_{\rm o}=17.480$ Å, $\beta_{\rm o}=111.84^\circ$

From these data, fractional atomic coordinates are shown in Table A.1.

In the calculation, we define the following new cell where the *a*-axis is parallel to layers 1 and 2: $a = -(a_{o} + c_{o}), b = -b_{o}, c = c_{o}$

Appendix B: Matrix elements of Hamiltonian

The matrix elements for HOMO–HOMO (H–H) are given by

$$\begin{split} h_{\rm H1,H1} &= b 1_{\rm H} (Y+Y) \,, \\ h_{\rm H1,H2} &= a 1_{\rm H} (XZ+Y) + a 2_{\rm H} (1+XYZ) \,, \\ h_{\rm H1,H3} &= p_{\rm H} (1+X+Y+XY) \,, \\ h_{\rm H1,H4} &= c 1_{\rm H} (1+\bar{Z}) + c 2_{\rm H} (Y+\bar{Y}\bar{Z}) \,, \\ h_{\rm H2,H2} &= b 2_{\rm H} (Y+\bar{Y}) \,, \\ h_{\rm H2,H3} &= c 1_{\rm H} (1+\bar{Z}) + c 2_{\rm H} (\bar{Y}+Y\bar{Z}) \,, \\ h_{\rm H2,H4} &= q_{\rm H} (\bar{X}\bar{Z}+\bar{Y}\bar{Z}+\bar{X}\bar{Y}\bar{Z}+\bar{Z}) \,, \\ h_{\rm H3,H3} &= b 1_{\rm H} (Y+\bar{Y}) \,, \\ h_{\rm H3,H4} &= a 1_{\rm H} (1+\bar{X}\bar{Y}\bar{Z}) + a 2_{\rm H} (\bar{X}\bar{Z}+\bar{Y}) \,, \end{split}$$

 $h_{\rm H4,H4} = b 2_{\rm H} (Y + \bar{Y}) ,$

The matrix elements for HOMO–LUMO (H-L) are given by

$h_{\rm H1,L1}$	=	$b1_{ m HL}(ar{Y}-Y)$,
$h_{\rm H1,L2}$	=	$a1_{\rm HL}(Y - XZ) + a2_{\rm HL}(1 - XYZ) ,$
$h_{\rm H1,L3}$	=	$p1_{\rm HL}(1-XY) + p2_{\rm HL}(Y-X)$,
$h_{\rm H1,L4}$	=	$c1_{\rm HL}(1-\bar{Z}) + c2_{\rm HL}(Y-\bar{Y}\bar{Z}) ,$
$h_{\rm H2,L1}$	=	$a1_{\rm HL}(\bar{X}\bar{Z}-\bar{Y})+a2_{\rm HL}(1-\bar{X}\bar{Y}\bar{Z}) ,$
$h_{\rm H2,L2}$	=	$b2_{\rm HL}(\bar{Y}-Y)$,
$h_{\rm H2,L3}$	=	$c1_{\rm HL}(\bar{Z}-1) + c2_{\rm HL}(\bar{Y}-Y\bar{Z}) ,$
$h_{\rm H2,L4}$	=	$q 1_{\rm HL} (\bar{X} \bar{Y} \bar{Z} - \bar{Z}) + q 2_{\rm HL} (\bar{X} \bar{Z} - \bar{Y} \bar{Z}) ,$
$h_{\rm H3,L1}$	=	$p1_{\rm HL}(\bar{X} - \bar{Y}) + p2_{\rm HL}(\bar{X}\bar{Y} - 1)$,
$h_{\rm H3,L2}$	=	$c1_{\rm HL}(1-\bar{Z}) + c2_{\rm HL}(Y-\bar{Y}Z)$,
$h_{\rm H3,L3}$	=	$b1_{ m HL}(-ar{Y}+Y) \; ,$
$h_{\rm H3,L4}$	=	$a1_{\rm HL}(1-\bar{X}\bar{Y}\bar{Z})+a2_{\rm HL}(\bar{Y}-\bar{X}\bar{Z})\;,$
$h_{\rm H4,L1}$	=	$c1_{\rm HL}(1-Z) + c2_{\rm HL}(YZ - \bar{Y}) ,$
$h_{\rm H4,L2}$	=	$q1_{\rm HL}(XZ - YZ) + q2_{\rm HL}(XYZ - Z) ,$
$h_{\rm H4,L3}$	=	$a1_{\rm HL}(1-XYZ) + a2_{\rm HL}(XZ-Y) ,$
$h_{\rm H4,L4}$	=	$b2_{\rm HL}(\bar{Y}-Y)$,

The matrix elements for LUMO-LUMO (L-L) are given by

$h_{\rm L1,L1}$	=	$\Delta E + b 1_{\mathrm{L}} (Y + \bar{Y}) \; ,$
$h_{\rm L1,L2}$	=	$a1_{\rm L}(XZ+Y) + a2_{\rm L}(1+XYZ) ,$
$h_{\rm L1,L3}$	=	$p_{\rm L}(1+X+Y+XY) ,$
$h_{\rm L1,L4}$	=	$c1_{\rm L}(1+\bar{Z}) + c2_{\rm L}(Y+\bar{Y}\bar{Z})$,
$h_{\rm L2,L2}$	=	$\Delta E + b 2_{\rm L} (Y + \bar{Y}) \; ,$
$h_{\rm L2,L3}$	=	$-c1_{\rm L}(1+\bar{Z}) - c2_{\rm L}(\bar{Y}+Y\bar{Z})$,
$h_{\rm L2,L4}$	=	$q_{\rm L}(\bar{X}\bar{Z}+\bar{Y}\bar{Z}+\bar{X}\bar{Y}\bar{Z}+\bar{Z}) ,$
$h_{\rm L3,L3}$	=	$\Delta E + b 1_{\mathrm{L}} (Y + \bar{Y}) \; ,$
$h_{\rm L3,L4}$	=	$-a1_{\rm L}(1+\bar{X}\bar{Y}\bar{Z})-a2_{\rm L}(\bar{X}\bar{Z}+\bar{Y})$,
$h_{\rm L4,L4}$	=	$\Delta E + b 2_{\rm L} (Y + \bar{Y}) \; .$

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